## B.E/B.TECH, M.E/M.TECH, MBA, MCA, POLYTECHNIC & SCHOOLS

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	Reg. No.:	*1 V
	00077	
	Question Paper Code: 60055	
	B.E./B.Tech. DEGREE EXAMINATIONS, APRIL/MAY 2022.	
	Second Semester	
	Electronics and Communication Engineering	
	PH3254 – PHYSICS FOR ELECTRONICS ENGINEERING	
	(Common to: Electronics and Telecommunication Engineering)	
	(Regulations 2021)	
Tim	ne : Three hours Maximum : 100 marks Answer ALL questions.	
	PART A — $(10 \times 2 = 20 \text{ marks})$	
1.	For a cubic system, sketch the planes with Miller Indices (110) and (011).	
2.	Define the terms linear and planar densities.	
3.	List out the three main theories developed for understating the properties of metals.	
4.	On the basis of spin how are the materials classified?	
5.	State the properties of a semiconductor.	
6.	Give any two differences between Schottky diode and Ohmic contacts.	3
7.	What are the main requirements for a suitable LED material?	
8.	Define the term plasmonics.	
9.	What is a quantum structure?	
10.	What is spintronics? Give its applications.	
	PART B — $(5 \times 16 = 80 \text{ marks})$	
11.	(a) Describe the seven systems of crystals with suitable diagrams and give the relation of lengths of axes and the relation between the axes of a unit cell in each type.	
	Or	
	(b) Classify and explain the various types of crystal defects with neat diagram.	

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		Don't all here the second representation	
		pursual properties and appropriate of ONT.	
	(b)	Describe the CNT structures in detail with illustrations. Mention physical properties and applications of CNT.	the
		Or Or of the second side of the	
15.	(a)	Explain the density of states in quantum well, quantum wire a quantum dot structure.	nd
	(b)	Explain the construction and working of optoelectronic device made up many layers with organic molecules of different conductivity levels.	of
		Or	
14.	(a)	Discuss about the optical processes in semiconductors and in quant well.	um
	(b)	What is Hall Effect? Derive an expression of Hall Coefficient RH n-type semiconductor. Give the experimental determination of H Effect. Write its applications and importance.	for [all
		Or SAME SAME SAME SAME SAME SAME SAME SAME	
		<ul> <li>Briefly describe the variation of carrier concentration w temperature.</li> </ul>	ith (4)
13.	(a)	assume as fermed as	12)
	(b)	Discuss about the origin of ferromagnetism and exchange interaction ferromagnetic materials.	in
		Or	
12.	(a)	Write a short note on Tight Binding Approximation for energy band solids. Derive the expression for effective mass of an electron and give concept of hole.	

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